Product data sheet

1. General description

The 74HC21 is a high-speed Si-gate CMOS device and is pin compatible with low-power Schottky TTL (LSTTL).

The 74HC21 provide the 4-input AND function.

2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C.

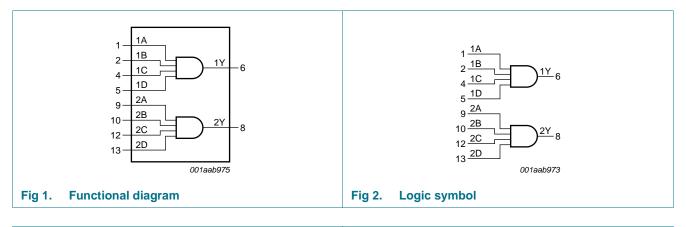
3. Ordering information

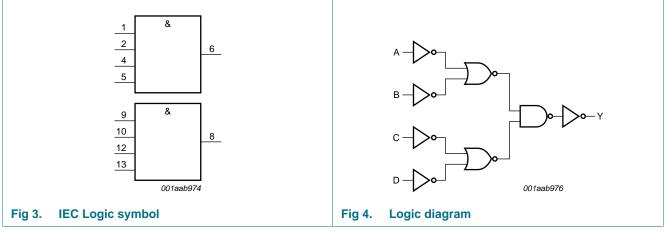
Table 1.Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
74HC21N	–40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1			
74HC21D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1			
74HC21DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1			
74HC21PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1			



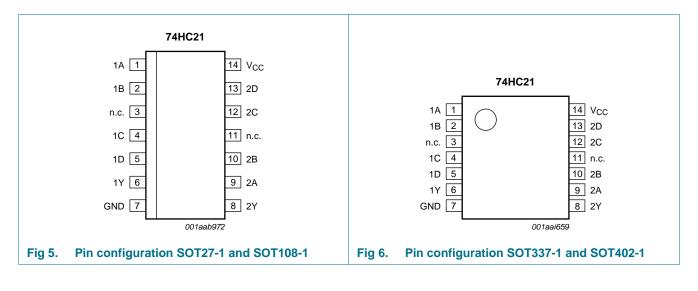
4. Functional diagram





5. Pinning information

5.1 Pinning



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5.2 Pin description

Table 2. Pin description		
Symbol	Pin	Description
1A, 1B, 1C, 1D	1, 2, 4, 5	data input
n.c.	3, 11	not connected
1Y	6	data output
GND	7	ground (0 V)
2Y	8	data output
2A, 2B, 2C, 2D	9, 10, 12, 13	data input
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table^[1]

Input				Output
nA	nB	nC	nD	nY
L	Х	X	X	L
Х	L	Х	Х	L
Х	Х	L	Х	L
Х	Х	Х	L	L
Н	Н	Н	Н	Н

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

				10	,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	V_O < –0.5 V or V_O > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
I _O	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2]		
	DIP14 package		-	750	mW
	SO14 and (T)SSOP14 packages		-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP14 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

For SO14 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

•		,				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
$\Delta t/\Delta V$	input transition rise and fall	$V_{CC} = 2.0 V$	-	-	625	ns/V
rate	rate	$V_{CC} = 4.5 V$	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = -20 μ A; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I_{O} = –20 $\mu A;$ V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I_{O} = –20 $\mu A;$ V_{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{\rm O}$ = –4.0 mA; $V_{\rm CC}$ = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = –5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = 20 μ A; V_{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 20 μ A; V_{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current		-	-	2.0	-	20	-	40	μΑ
CI	input capacitance		-	3.5	-	-	-	-	-	pF

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10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; test circuit see <u>Figure 8</u>.

Symbol Parameter		Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{pd} propagation delay		nA, nB, nC or nD to nY; see <u>Figure 7</u>	<u>1]</u>			"				
		$V_{CC} = 2.0 V$	-	33	110	-	140	-	165	ns
		$V_{CC} = 4.5 V$	-	12	22	-	28	-	33	ns
		$V_{CC} = 6.0 V$	-	10	19	-	24	-	28	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	10	-	-	-	-	-	ns
t _t	transition time	nY output; see Figure 7	2]							
		$V_{CC} = 2.0 V$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$	-	6	13	-	16	-	19	ns
C _{PD}	power dissipation capacitance	$V_{I} = GND$ to V_{CC}	3] _	15	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 \sum (C_L \times V_{CC}^2 \times f_o) = sum of outputs.

11. Waveforms

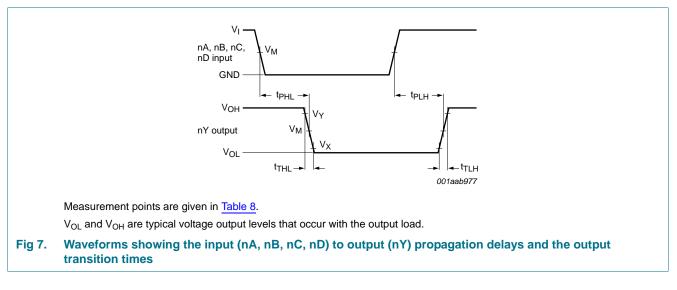


Table 8. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC21	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}

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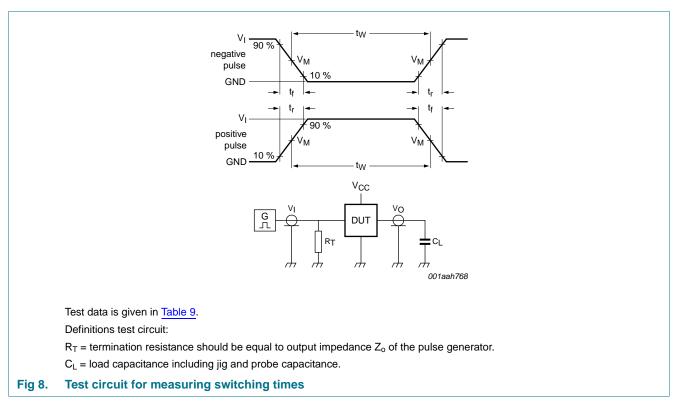


Table 9. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74HC21	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}



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12. Package outline

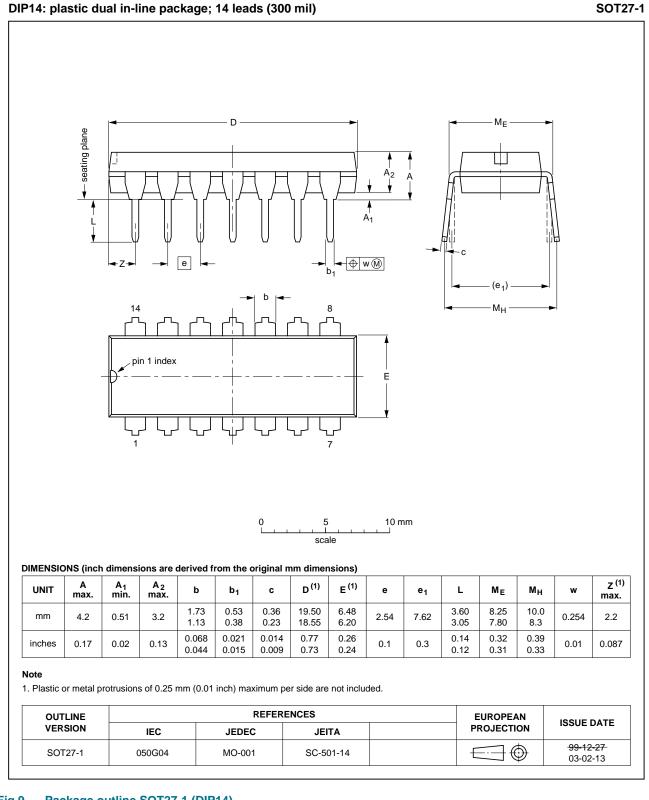
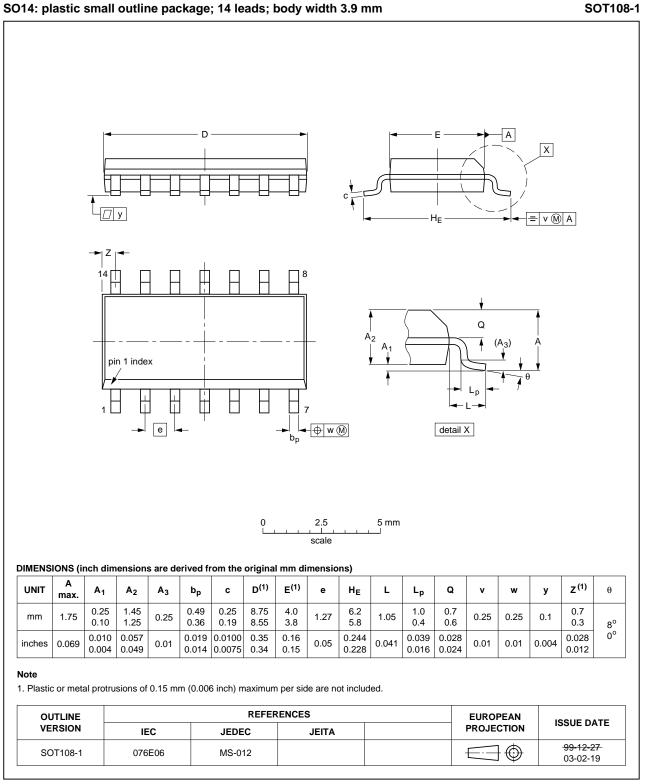


Fig 9. Package outline SOT27-1 (DIP14)

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

Fig 10. Package outline SOT108-1 (SO14)

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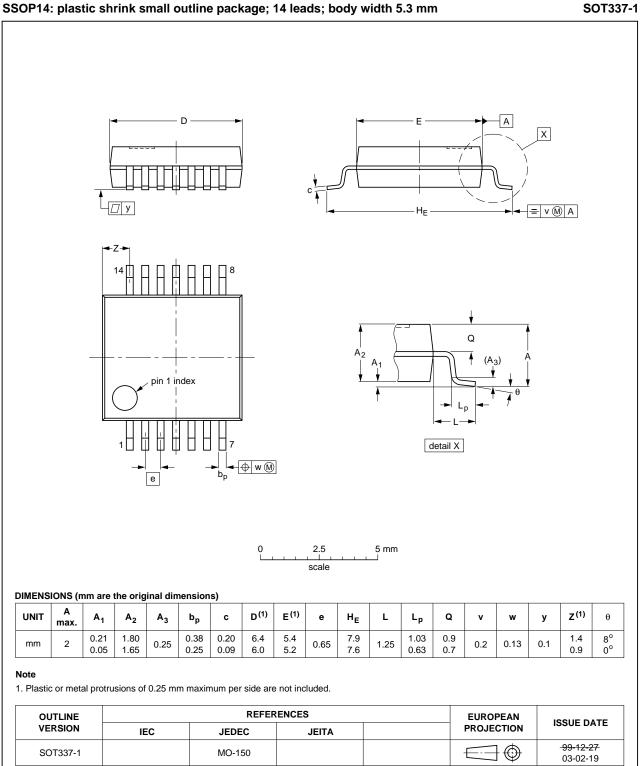


Fig 11. Package outline SOT337-1 (SSOP14)

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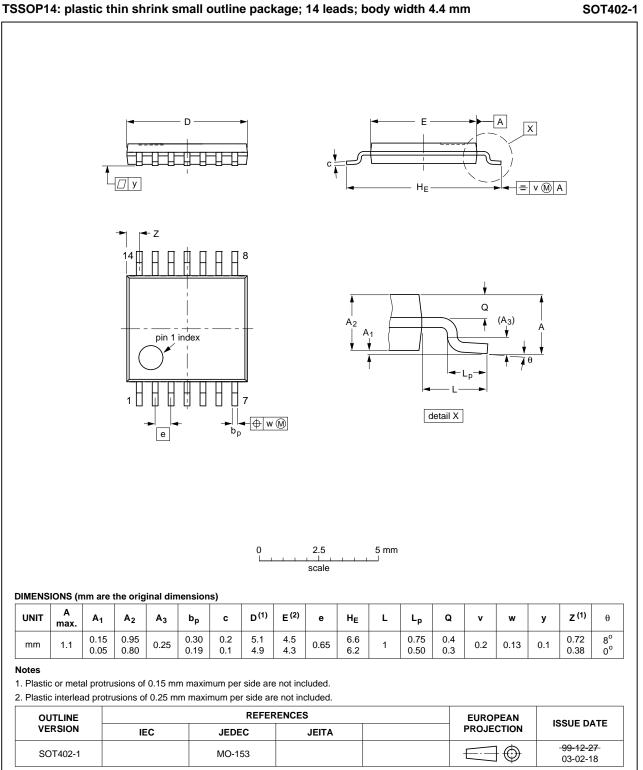


Fig 12. Package outline SOT402-1 (TSSOP14)

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13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision his	tory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC21 v.6	20130208	Product data sheet	-	74HC21 v.5
Modifications:	Section 2: Type	corrected in the specified to	emperature range.	
74HC21 v.5	20090507	Product data sheet	-	74HC21 v.4
Modifications:	<u>Table 1</u> : Type n	umber 74HCT21PW change	ed to 74HC21PW.	
74HC21 v.4	20090407	Product data sheet	-	74HC21 v.3
Modifications:		of this data sheet has been miconductors.	redesigned to comply v	vith the new identity guidelines
	 Legal texts 	have been adapted to the r	new company name wh	ere appropriate.
	 Added type 	e number 74HC21PW (TSS	OP14 package).	
74HC21 v.3	20041112	Product data sheet	-	74HC_HCT21_CNV v.2
74HC_HCT21_CNV v.2	19970828	Product specification	-	74HC_HCT21 v.1
74HC_HCT21 v.1	19901201	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 8 February 2013 Document identifier: 74HC21